NSN 5962-01-129-1910

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View Online at https://aerobasegroup.com/nsn/5962-01-129-1910

Body Length:

Between 0.880 inches and 0.920 inches

Body Width:

Between 0.265 inches and 0.310 inches

Body Height:

Between 0.140 inches and 0.165 inches

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Rf4c ground s 99696

Features Provided:

Hermetically sealed and high performance and high reliability and 3-state output

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Metal oxide-semiconductor logic

Input Circuit Pattern:

12 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-3.5 volts power source and 7.0 volts power source

Time Rating Per Chacteristic:

250.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Ram

Memory Capacity:

Unknown

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

18 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

